TENTATIVE

TOSHIBA Photocoupler GaAs Ired & Photo-Transistor

TLP141G

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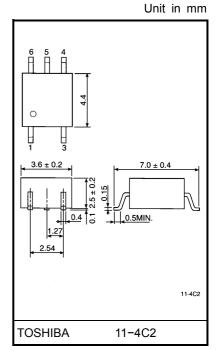
Programmable Controllers
AC-Output Module
Solid State Relay

The TOSHIBA mini flat coupler TLP141G is a small outline coupler, suitable for surface mount assembly.

The TLP141G consists of a photo thyristor, optically coupled to a gallium arsenide infrared emitting diode.

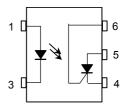
Peak off-state voltage: 400 V (min.)
Trigger LED current: 10 mA (max.)
On-state current: 150 mA (max.)
Isolation voltage: 2500 Vrms (min.)

• UL recognized: UL1577, file no. E67349



Weight: 0.09 g

Pin Connections



- 1 : Anode
- 3 : Cathode
- 4 : Cathode
- 5 : Anode.
- 6 : Gate

Maximum Ratings (Ta = 25°C)

	Characteristic	Symbol	Rating	Unit	
	Forward current	IF	50	mA	
	Forward current derating (Ta ≥ 53°C)	ΔI _F /°C	-0.7	mA / °C	
LED	Peak forward current (100 µs pulse, 100 pps)	I _{FP}	1	Α	
	Reverse voltage	V _R	5	V	
	Junction temperature	Tj	125	°C	
	Peak forward voltage($R_{GK} = 27k\Omega$)	V_{DRM}	400	V	
Detector	Peak reverse voltage(R _{GK} = 27kΩ)	V_{DRM}	400	V	
	On–state current	I _{T(RMS)}	150	mA	
	On–state current derating (Ta ≥ 25°C)	ΔI _T / °C	-2.0	mA / °C	
	Peak one cycle surge current	I _{TSM}	2	Α	
	Peak reverse gate voltage	V_{GM}	5	V	
	Junction temperature	Tj	100	°C	
Storage	e temperature range	T _{stg}	-55~125	°C	
Operat	ing temperature range	T _{opr}	-55~100	°C	
Lead s	oldering temperature (10 s)	T _{sol}	260	°C	
Isolatio	n voltage (AC, 1 min., RH ≤ 60%) (Note 1)	BV_S	2500	Vrms	

(Note 1) Device considered a two terminal device: pins 1 and 3 shorted together and pins 4, 5 and 6 shorted together.

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Recommended Operating Conditions

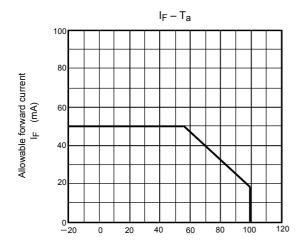
Characteristic	Symbol	Min.	Тур.	Max.	Unit
Supply voltage	V_{AC}	_	_	120	Vac
Forward current	I _F	15	20	25	mA
Operating temperature	T _{opr}	-25	_	85	°C
Gate to cathode resistance	R _{GK}	_	27	33	kΩ
Gate to cathode capacitance	C _{GK}	-	0.01	0.1	μF

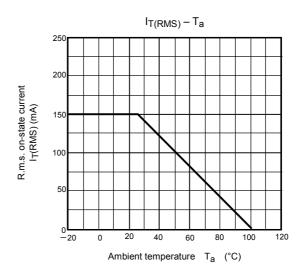
Individual Electrical Characteristics (Ta = 25°C)

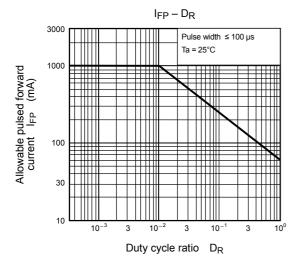
Characteristic		Symbol	Test Condition		Min.	Тур.	Max.	Unit
LED	Forward voltage	V _F	I _F = 10 mA		1.0	1.15	1.3	V
	Reverse current	I _R	V _R = 5 V		_	_	10	μΑ
	Capacitance	C _T	V = 0, f = 1 MHz		_	30	_	pF
Detector	Off-state current	I _{DRM}	V _{AK} = 400 V R _{GK} = 27 kΩ	Ta = 25°C	_	10	5000	nA
				Ta = 100°C	_	1	100	μA
	Reverse current	I _{RRM}	V _{KA} = 70 mA	Ta = 25°C	_	10	5000	nA
			R_{GK} = 27 k Ω	Ta = 100°C	_	1	100	μΑ
	On-state voltage	V _{TM}	I _{TM} = 100 mA		_	0.9	1.3	V
	Holding current	lΗ	R _{GK} = 27 kΩ		_	0.2	1	mA
	Off-state dv / dt	dv/dt	V _{AK} = 280 V, R _{GK} = 27 kΩ		5	10	_	V / µs
	Capacitance C _j V	C.	V = 0, f = 1 MHz	Anode to gate	_	20	_	ηE
			Gate to cathode	_	350	_	pF	

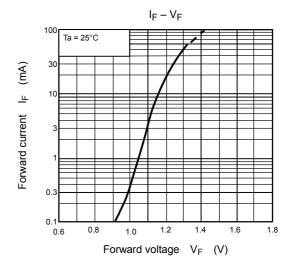
Coupled Characteristics (Ta = 25°C)

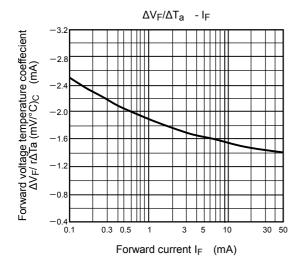
Characteristic	Symbol	Test Condition	Min.	Тур.	Max.	Unit
Trigger LED current	I _{FT}	$V_{AK} = 6 \text{ V}, R_{GK} = 27 \text{k}\Omega$	_	4	10	mA
Turn-on time	t _{on}	I_F = 50mA, R_{GK} = 27kΩ	_	10	_	μs
Coupled dv / dt	dv/dt	$V_S = 500 \text{ V}, R_{GK} = 27 \text{k}\Omega$	500	_	_	V / µs
Capacitance (input to output)	C _S	V _S = 0, f = 1 MHz	_	0.8	_	pF
Isolation resistance	R _S	V _S = 500 V, R.H. ≤ 60%	5×10 ¹⁰	10 ¹⁴	_	Ω
		AC, 1 minute	2500	_	_	Vrms
Isolation voltage		AC, 1 second, in oil	_	5000	_	VIIIIS
		DC, 1 minute, in oil	_	5000	_	Vdc

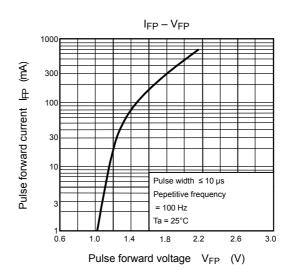


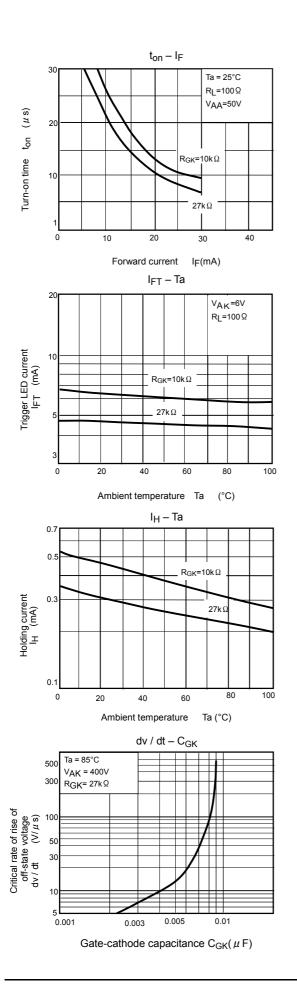


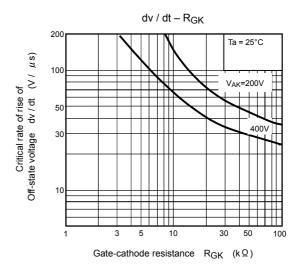


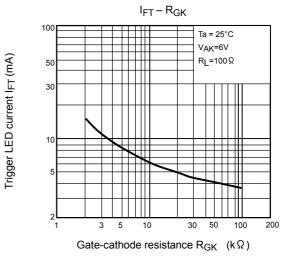


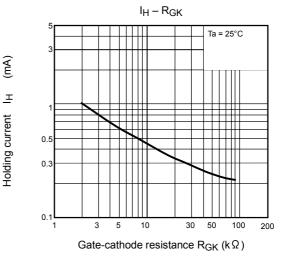












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